

# High Voltage Thyristor \ Diode Module

$V_{RRM}$  = 2x2200 V

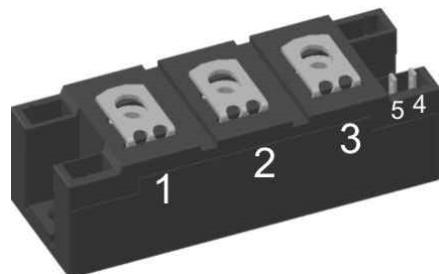
$I_{TAV}$  = 220 A

$V_T$  = 1.19 V

## Phase leg

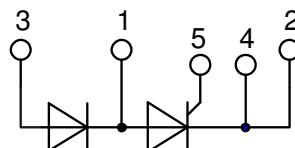
### Part number

MCNA220PD2200YB



Backside: isolated

E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: Y4

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Terms .Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

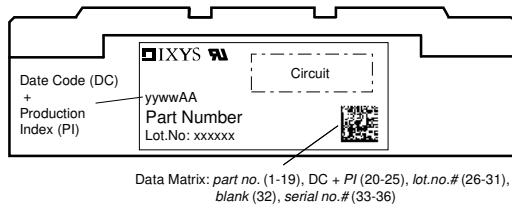
Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;
- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.



**Package Y4**

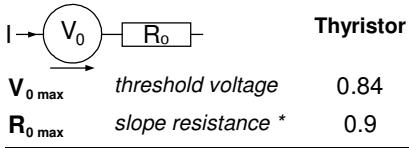
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	<i>RMS current</i>	per terminal			300	A
$T_{VJ}$	<i>virtual junction temperature</i>		-40		140	°C
$T_{op}$	<i>operation temperature</i>		-40		125	°C
$T_{stg}$	<i>storage temperature</i>		-40		125	°C
<b>Weight</b>				150		g
$M_D$	<i>mounting torque</i>		2.25		2.75	Nm
$M_T$	<i>terminal torque</i>		4.5		5.5	Nm
$d_{Spp/App}$	<i>creepage distance on surface / striking distance through air</i>	<i>terminal to terminal</i>	14.0	10.0		mm
$d_{Spb/Apb}$		<i>terminal to backside</i>	16.0	16.0		mm
$V_{ISOL}$	<i>isolation voltage</i>	$t = 1 \text{ second}$ $t = 1 \text{ minute}$ 50/60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA}$	4800 4000			V V

**Part description**

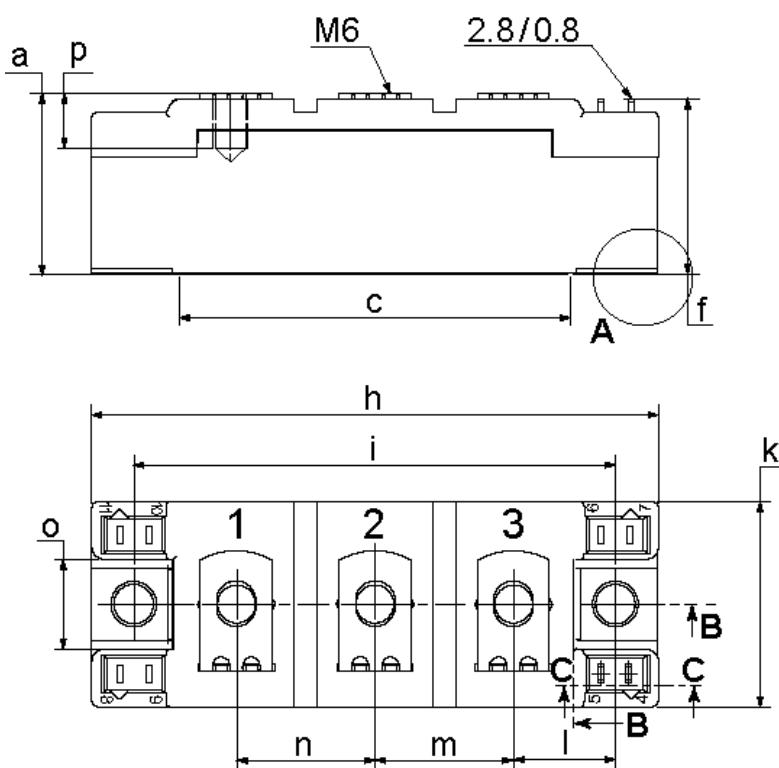
M = Module  
 C = Thyristor (SCR)  
 N = High Voltage Thyristor  
 A = ( $\geq 2000\text{V}$ )  
 220 = Current Rating [A]  
 PD = Phase leg  
 2200 = Reverse Voltage [V]  
 YB = Y4-M6

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCNA220PD2200YB	MCNA220PD2200YB	Box	6	520509

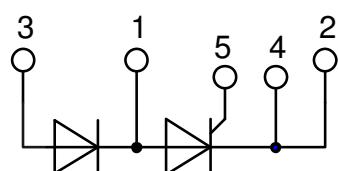
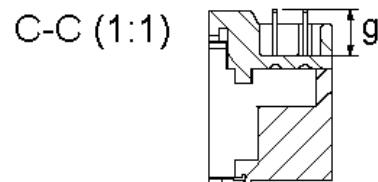
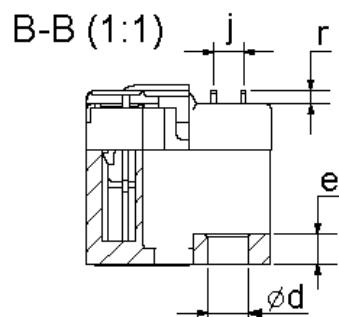
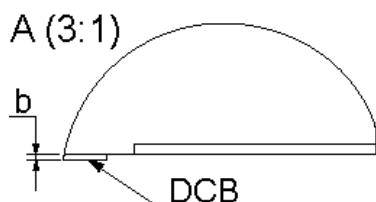
Similar Part	Package	Voltage class
MCNA150PD2200YB	Y4-M6	2200
MCNA180PD2200YB	Y4-M6	2200

**Equivalent Circuits for Simulation***\* on die level* $T_{VJ} = 140 \text{ °C}$ 

## Outlines Y4



Dim.	MIN [mm]	MAX [mm]	MIN [inch]	MAX [inch]
a	30.0	30.6	1.181	1.205
b	typ. 0.25		typ. 0.010	
c	64.0	65.0	2.520	2.559
d	6.5	7.0	0.256	0.275
e	4.9	5.1	0.193	0.201
f	28.6	29.2	1.126	1.150
g	7.3	7.7	0.287	0.303
h	93.5	94.5	3.681	3.720
i	79.5	80.5	3.130	3.169
j	4.8	5.2	0.189	0.205
k	33.4	34.0	1.315	1.339
l	16.7	17.3	0.657	0.681
m	22.7	23.3	0.894	0.917
n	22.7	23.3	0.894	0.917
o	14.0	15.0	0.551	0.591
p	typ. 10.5		typ. 0.413	
r	1.8	2.4	0.071	0.041



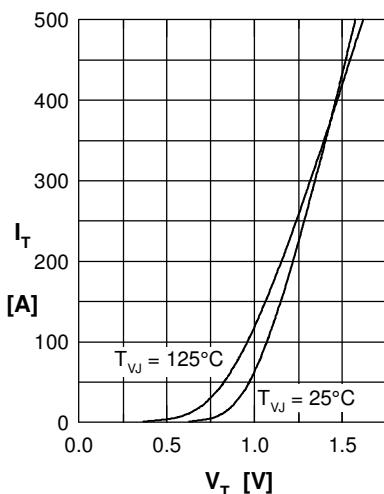
**Thyristor**

Fig. 1 Forward characteristics

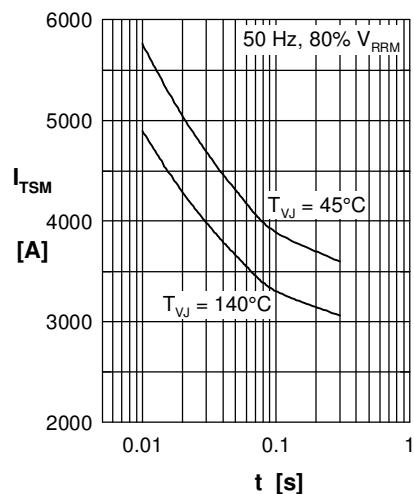
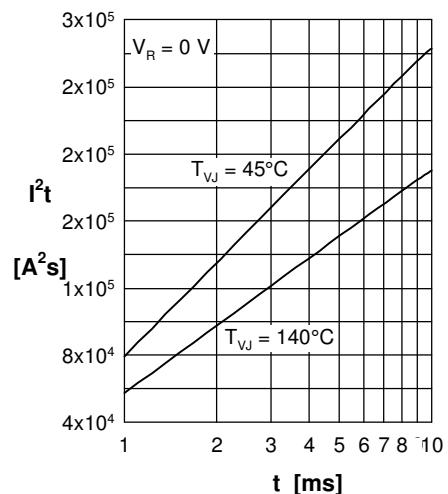
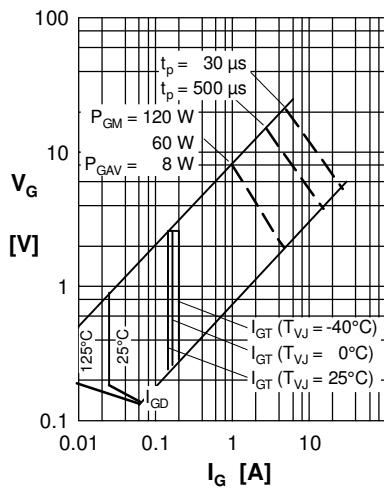
Fig. 2 Surge overload current  
 $I_{TSM}$ : crest value,  $t$ : durationFig. 3  $I^2t$  versus time (1-10 s)

Fig. 4 Gate voltage &amp; gate current

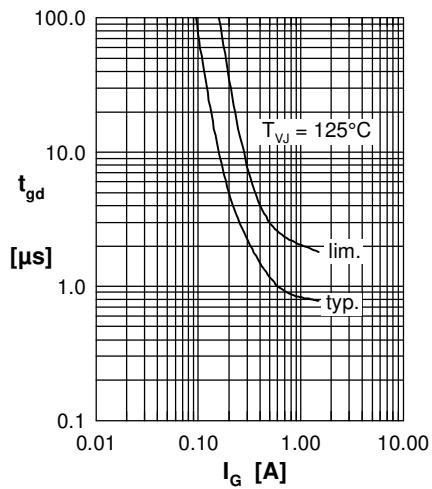
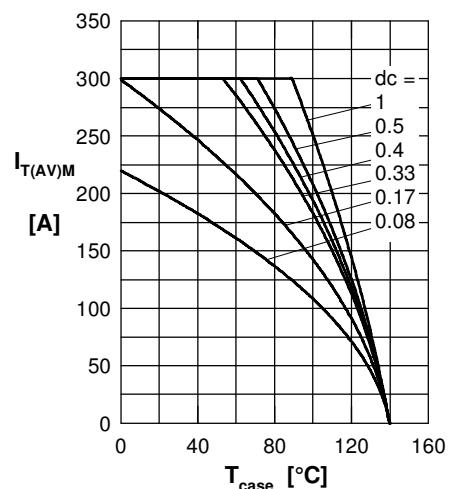
Fig. 5 Gate controlled delay time  $t_{gd}$ 

Fig. 6 Max. forward current at case temperature

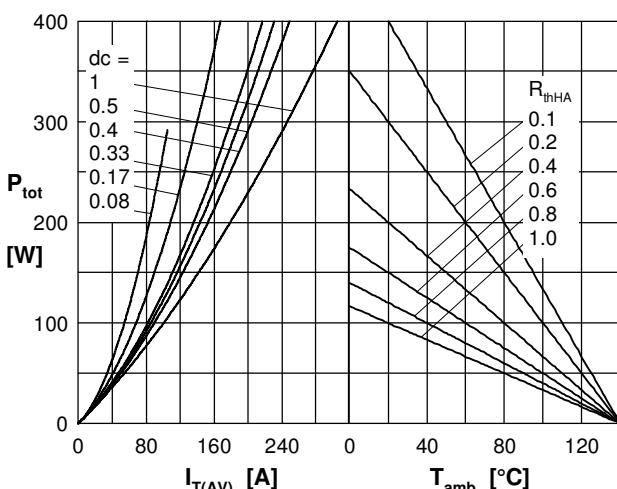
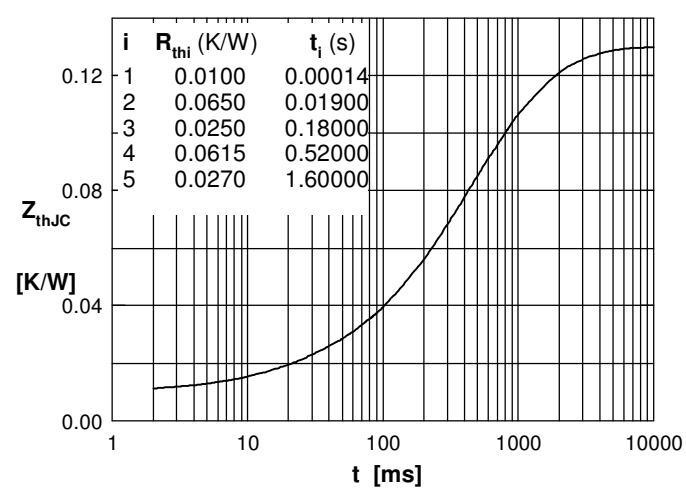
Fig. 7a Power dissipation versus direct output current  
Fig. 7b and ambient temperature

Fig. 8 Transient thermal impedance junction to case